

RM6005AR

N-Channel Enhancement Mode Power MOSFET

Description

The RM6005AR uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

- V_{DS}=60V,I_D=5A
 R_{DS(ON)} <35mΩ @ V_{GS}=10V (Typ.26mΩ)
 R_{DS(ON)} <45mΩ @ V_{GS}=4.5V (Typ.32mΩ)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply
- Halogen-free
- P/N suffix V means AEC-Q101 qualified, e.g:RM6005ARV

Package Marking and Ordering Information

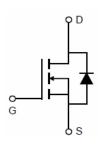
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
6005AR	RM6005AR	SOT-223-3L	Ø330mm	12mm	2500 units

Absolute Maximum Ratings (T_A=25[°]Cunless otherwise noted)

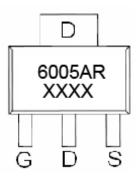
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι _D	5	А
Drain Current-Continuous(T _c =100℃)	I _D (100℃)	3.5	A
Pulsed Drain Current	I _{DM}	24	A
Maximum Power Dissipation	PD	2	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{θJA}	62.5	°C/W
--------------------------------------------------	------------------	------	------



Schematic diagram



SOT-223-3L view

Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	60	-	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	μA	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1.2	1.6	2.5	V	
	R _{DS(ON)}	V _{GS} =10V, I _D =5A	-	26	35	mΩ	
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =5A	-	32	45	mΩ	
Forward Transconductance	g fs	V _{DS} =5V,I _D =5A	11	-	-	S	
Dynamic Characteristics (Note4)			•				
Input Capacitance	C _{lss}		-	979	-	PF	
Output Capacitance	C _{oss}	V_{DS} =30V, V_{GS} =0V,	-	120	-	PF	
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	100	-	PF	
Switching Characteristics (Note 4)	I						
Turn-on Delay Time	t _{d(on)}		-	5.2	-	nS	
Turn-on Rise Time	tr	V _{DD} =30V, R _L =6.7Ω	-	3	-	nS	
Turn-Off Delay Time	t _{d(off)}	V _{GS} =10V,R _G =3Ω	-	17	-	nS	
Turn-Off Fall Time	t _f		-	2.5	-	nS	
Total Gate Charge	Qg		-	22		nC	
Gate-Source Charge	Q _{gs}	V_{DS} =30V,I _D =5A,	-	3.3		nC	
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	5.2		nC	
Drain-Source Diode Characteristics	I						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =5A	-		1.2	V	
Diode Forward Current (Note 2)	I _S			-	5	Α	
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)					

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

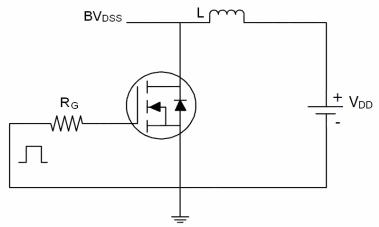
3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production

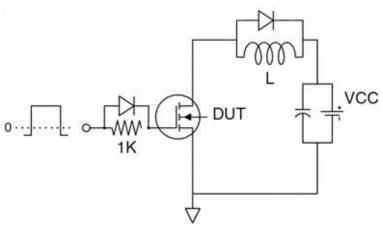
5. EAS condition:Tj=25 $^\circ\!\mathrm{C},VDD$ =30V,VG=10V,L=0.5mH,Rg=25 Ω



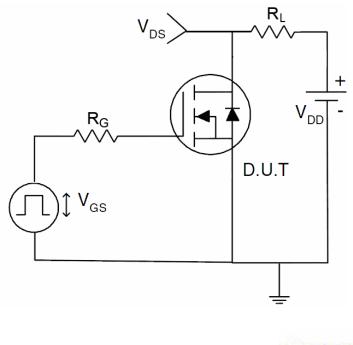
Test Circuit 1) E_{AS} test Circuit



2) Gate charge test Circuit

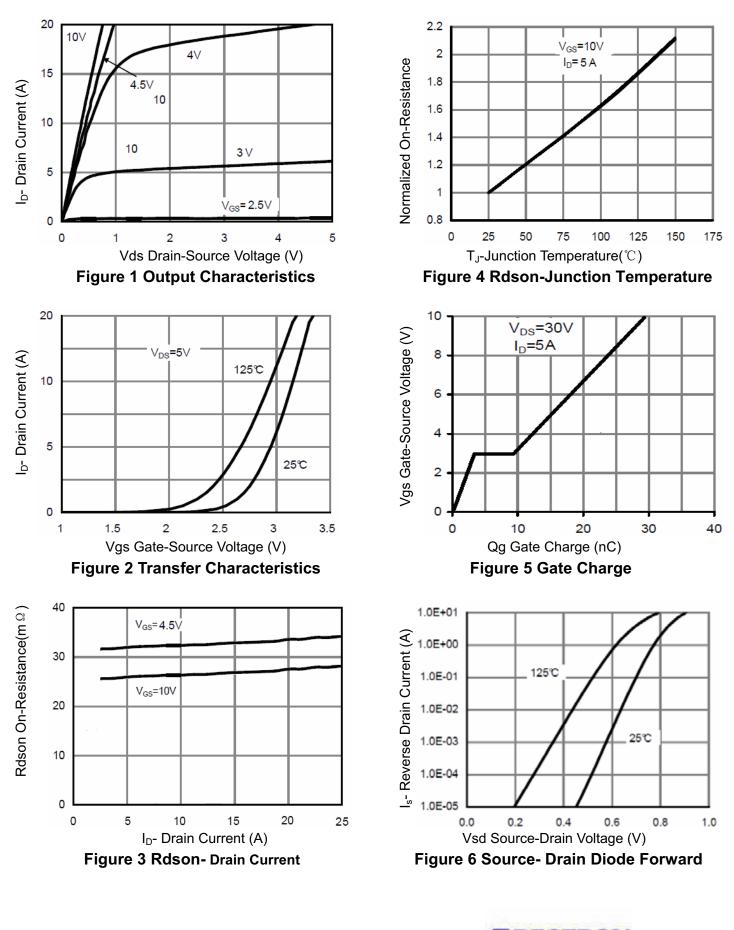


3) Switch Time Test Circuit



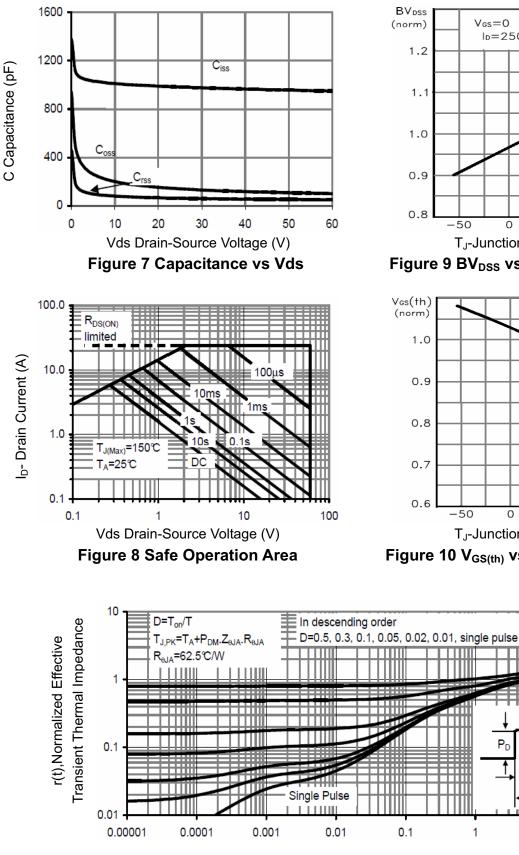
CRECTRON -

RATING AND CHARACTERISTICS CURVES (RM6005AR)



CRECTRON -

RATING AND CHARACTERISTICS CURVES (RM6005AR)



Square Wave Pluse Duration (sec) Figure 11 Normalized Maximum Transient Thermal Impedance

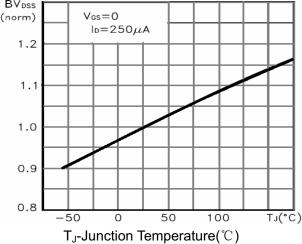


Figure 9 BV_{DSS} vs Junction Temperature

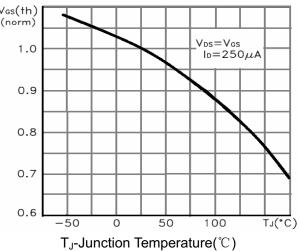


Figure 10 V_{GS(th)} vs Junction Temperature



1000

PD

t

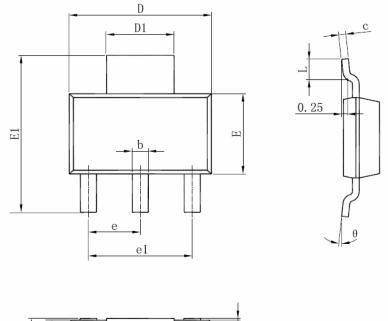
1

Ton

10

100

SOT-223-3L Package Information



A.] ₁
	1

Querra la	Dimensions Ir	n Millimeters	Dimensions	In Inches	
Symbol	Min	Max	Min	Max	
A	1.520	1.800	0.060	0.071	
A1	0.000	0.100	0.000	0.004	
A2	1.500	1.700	0.059	0.067	
b	0.660	0.820	0.026	0.032	
с	0.250	0.350	0.010	0.014	
D	6.200	6.400	0.244	0.252	
D1	2.900	3.100	0.114	0.122	
E	3.300	3.700	0.130	0.146	
E1	6.830	7.070	0.269	0.278	
e	2.300	(BSC)	0.091(BSC)		
e1	4.500	4.700	0.177	0.185	
L	0.900	1.150	0.035	0.045	
θ	0°	10°	0°	10°	

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



Package	Tube (pcs/tube)	Tube (pcs/inner box)	Tube (pcs/cartoon)	Tape&Reel (pcs/reel)	Tape&Reel (pcs/inner box)	Tape&Reel (pcs/cartoon)
DFN	100	10,000	100,000	2,500	5,000	40,000
SOP-8	100	10,000	100,000	4,000	4,000	20,000
TSSOP-8	100	32,000	128,000	3,000	6,000	48,000
SOT-23-3L				3,000	30,000	120,000
SOT-23-6L				3,000	30,000	120,000
SOT-23(6R)				3,000	30,000	120,000
SOT-363				3,000	30,000	120,000
SOT-523				3,000	30,000	120,000
SOT223				2,500	2,500	20,000
TO-220	50	1,000	5,000			
TO-220F	50	1,000	10,000			
TO-247	30	300	1,200			
TO-251	80	4,000	40,000			
TO-251S(4R)	80	4,000	40,000			
TO-252-2L(4R)	80	4,000	40,000	2,500	2,500	25,000
TO-263-2L	50	1,000	10,000	800	800	8,000
TO-3P	30	300	3,000			
TO-92				1,000(袋装)	10,000	100,000

DISCLAIMER NOTICE

Rectron Inc reserves the right to make changes without notice to any product specification herein, to make corrections, modifications, enhancements or other changes. Rectron Inc or anyone on its behalf assumes no responsibility or liability for any errors or inaccuracies. Data sheet specifications and its information contained are intended to provide a product description only. "Typical" parameters which may be included on RECTRON data sheets and/ or specifications can and do vary in different applications and actual performance may vary over time. Rectron Inc does not assume any liability arising out of the application or use of any product or circuit.

Rectron products are not designed, intended or authorized for use in medical, life-saving implant or other applications intended for life-sustaining or other related applications where a failure or malfunction of component or circuitry may directly or indirectly cause injury or threaten a life without expressed written approval of Rectron Inc. Customers using or selling Rectron components for use in such applications do so at their own risk and shall agree to fully indemnify Rectron Inc and its subsidiaries harmless against all claims, damages and expenditures.

